

LTC4251/LTC4251-1/ LTC4251-2

ABSOLUTE MAXIMUM RATINGS

(Note 1), All Voltages are Referred to V_{EE}

Current into V_{IN} (100 μ s Pulse)	100mA
Minimum V_{IN} Voltage	-0.3V
Gate, UV/OV, Timer Voltage	-0.3V to 16V
Sense Voltage	-0.6V to 16V
Current Out of Sense Pin (20 μ s Pulse)	-200mA
Maximum Junction Temperature	125°C
Operating Temperature Range	
LTC4251C/LTC4251-1C/LTC4251-2C	0°C to 70°C
LTC4251I/LTC4251-1I/LTC4251-2I	-40°C to 85°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

PACKAGE/ORDER INFORMATION

<p style="text-align: center;">TOP VIEW</p> <p style="text-align: center;">S6 PACKAGE 6-LEAD PLASTIC SOT-23 *UV FOR LTC4251-2 $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 256^{\circ}\text{C/W}$</p>	
ORDER PART NUMBER	S6 PART MARKING
LTC4251CS6	LTUQ
LTC4251IS6	LTUR
LTC4251-1CS6	LTQU
LTC4251-1IS6	LTQV
LTC4251-2CS6	LTK6
LTC4251-2IS6	LTAZ
<p>Order Options Tape and Reel: Add #TR Lead Free: Add #PBF Lead Free Tape and Reel: Add #TRPBF Lead Free Part Marking: http://www.linear.com/leadfree/</p>	

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}\text{C}$. (Notes 2, 3)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
V_Z	V_{IN} to V_{EE} Zener Voltage	$I_{IN} = 2\text{mA}$	● 11.5	13	14.5	V	
r_Z	V_{IN} to V_{EE} Zener Dynamic Impedance	$I_{IN} = 2\text{mA}$ to 30mA		5		Ω	
I_{IN}	V_{IN} Supply Current	UV/OV = 4V, $V_{SENSE} = V_{EE}$, $V_{GATE} = 0\text{V}$ (Sourcing)	●	0.8	2	mA	
V_{LKO}	V_{IN} Undervoltage Lockout	Coming out of UVLO (Rising V_{IN})	●	9.2	11.5	V	
V_{LKH}	V_{IN} Undervoltage Lockout Hysteresis			1		V	
V_{CB}	Circuit Breaker Current Limit Voltage	$V_{CB} = (V_{SENSE} - V_{EE})$	●	40	50	60	mV
V_{ACL}	Analog Current Limit Voltage	$V_{ACL} = (V_{SENSE} - V_{EE})$	●	80	100	120	mV
V_{FCL}	Fast Current Limit Voltage	$V_{FCL} = (V_{SENSE} - V_{EE})$	●	150	200	300	mV
I_{GATE}	GATE Pin Output Current	UV/OV = 4V, $V_{SENSE} = V_{EE}$, $V_{GATE} = 0\text{V}$ (Sourcing) UV/OV = 4V, $V_{SENSE} - V_{EE} = 0.15\text{V}$, $V_{GATE} = 3\text{V}$ (Sinking) UV/OV = 4V, $V_{SENSE} - V_{EE} = 0.3\text{V}$, $V_{GATE} = 1\text{V}$ (Sinking)	●	40	58	80	μA mA mA
V_{GATE}	External MOSFET Gate Drive	$V_{GATE} - V_{EE}$, $I_{IN} = 2\text{mA}$	●	10	12	V_Z	V
V_{GATEL}	Gate Low Threshold	(Before Gate Ramp-Up)		0.5		V	
V_{UVHI}	UV Threshold High	LTC4251/LTC4251-2 LTC4251-1	● ●	3.075 2.300	3.225 2.420	3.375 2.540	V V
V_{UVLO}	UV Threshold Low	LTC4251/LTC4251-2 LTC4251-1	● ●	2.775 2.050	2.925 2.160	3.075 2.270	V V
V_{UVHST}	UV Hysteresis	LTC4251/LTC4251-2 LTC4251-1		0.30 0.26		V V	
V_{OVHI}	OV Threshold High	LTC4251 LTC4251-1	● ●	5.85 5.86	6.15 6.17	6.45 6.48	V V

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ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Notes 2, 3)

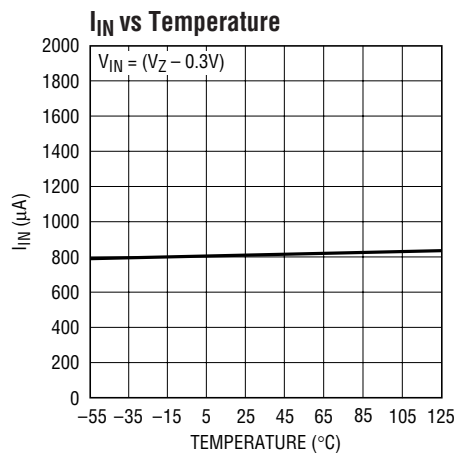
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OVLO}	OV Threshold Low	LTC4251	● 5.25	5.55	5.85	V
		LTC4251-1	● 5.61	5.91	6.21	V
V_{OVHST}	OV Hysteresis	LTC4251		0.60		V
		LTC4251-1		0.26		V
I_{SENSE}	SENSE Input Current	UV/OV = 4V, $V_{SENSE} = 50\text{mV}$	● -30	-15		μA
I_{INP}	UV/OV Input Current	UV/OV = 4V	●	± 0.1	± 1	μA
V_{TMRH}	Timer Voltage High Threshold			4		V
V_{TMRL}	Timer Voltage Low Threshold			1		V
I_{TMR}	Timer Current	Timer On (Initial Cycle, Sourcing), $V_{TMR} = 2\text{V}$		5.8		μA
		Timer Off (Initial Cycle, Sinking), $V_{TMR} = 2\text{V}$		28		mA
		Timer On (Circuit Breaker, Sourcing), $V_{TMR} = 2\text{V}$		230		μA
		Timer Off (Cooling Cycle, Sinking), $V_{TMR} = 2\text{V}$		5.8		μA
t_{PLUG}	UV Low to GATE Low			0.7		μs
t_{PHLOG}	OV High to GATE Low	LTC4251/LTC4251-1		1		μs

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

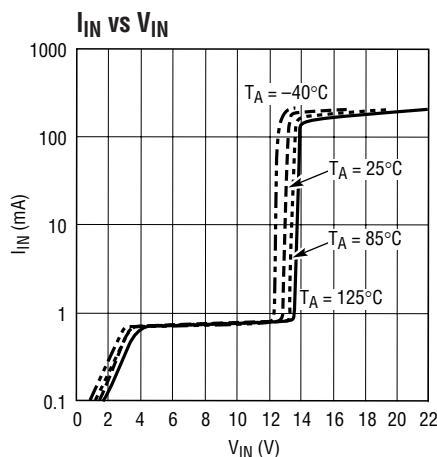
Note 2: All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to V_{EE} unless otherwise specified.

Note 3: UV/OV = 4V refers to UV = 4V for the LTC4251-2.

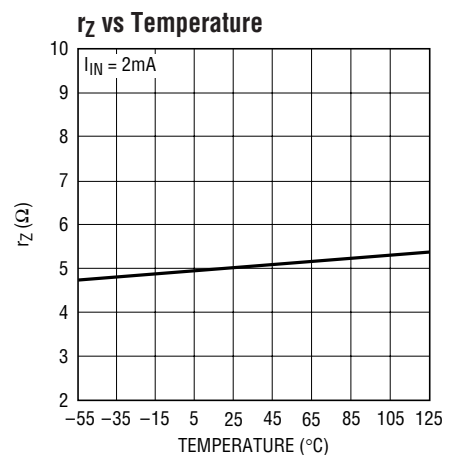
TYPICAL PERFORMANCE CHARACTERISTICS UV/OV = 4V refers to UV = 4V for the LTC4251-2.



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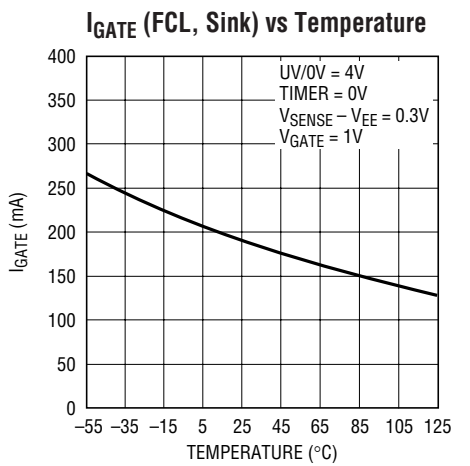
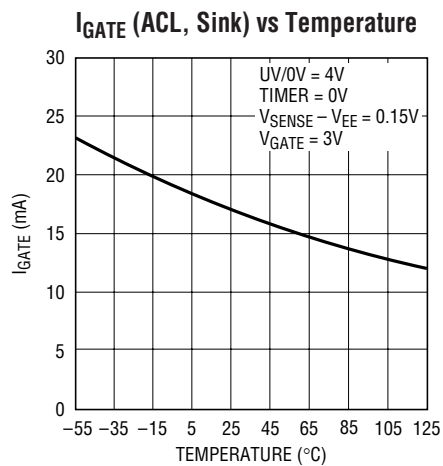
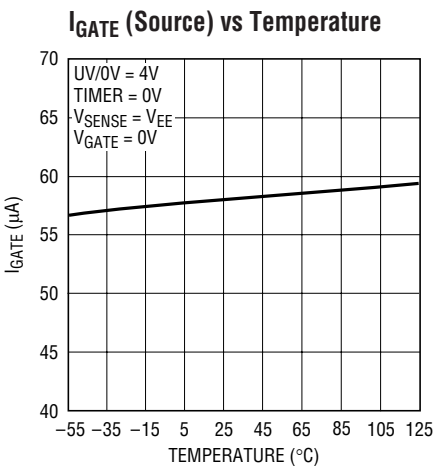
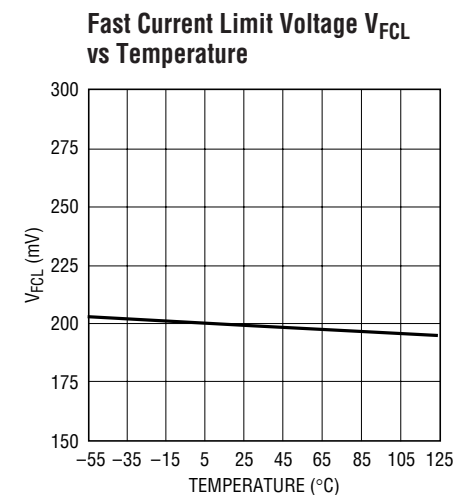
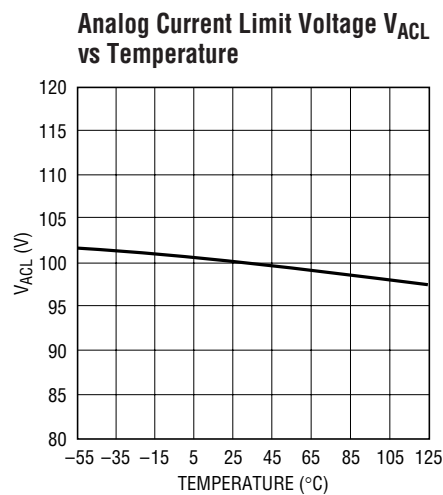
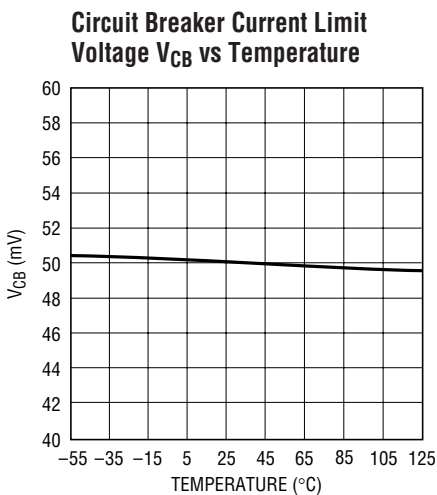
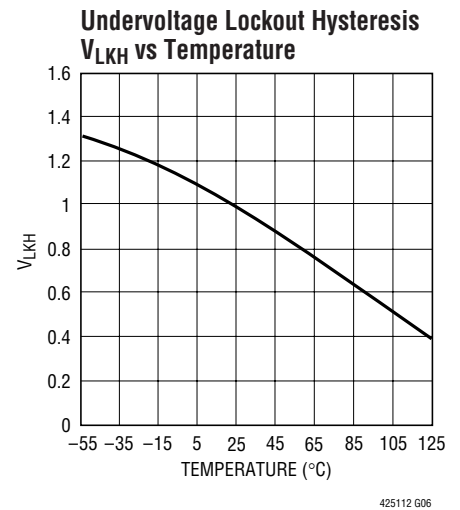
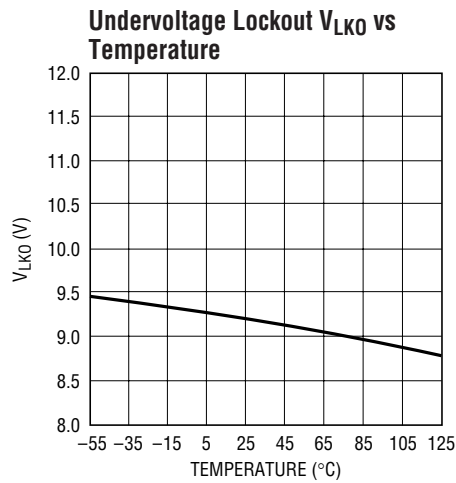
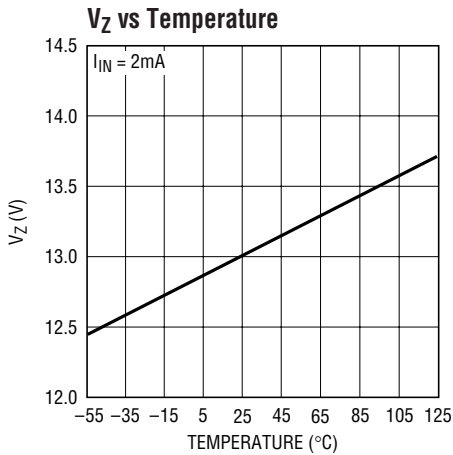


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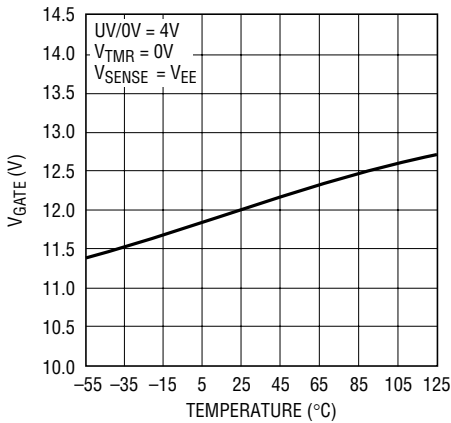
425112 G03

TYPICAL PERFORMANCE CHARACTERISTICS UV/OV = 4V refers to UV = 4V for the LTC4251-2.



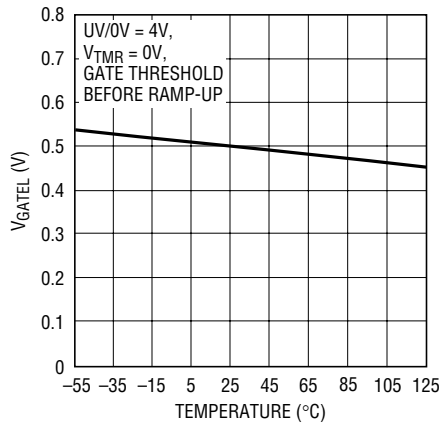
TYPICAL PERFORMANCE CHARACTERISTICS UV/OV = 4V refers to UV = 4V for the LTC4251-2.

V_{GATE} vs Temperature



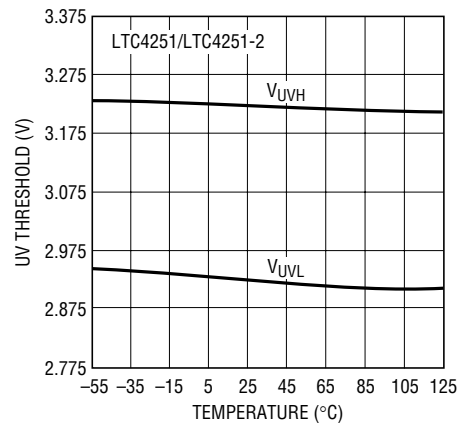
425112 G13

V_{GATEL} vs Temperature



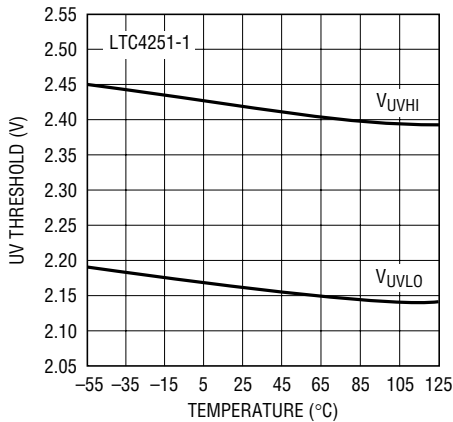
425112 G14

UV Threshold vs Temperature



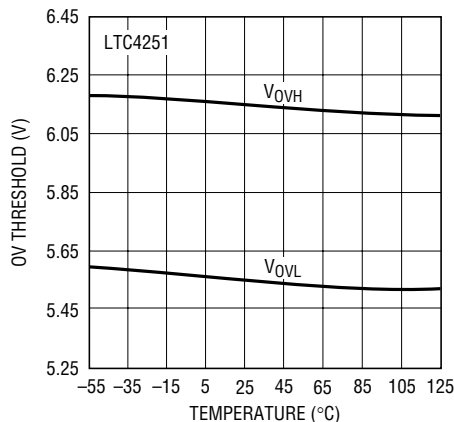
425112 G15

UV Threshold vs Temperature



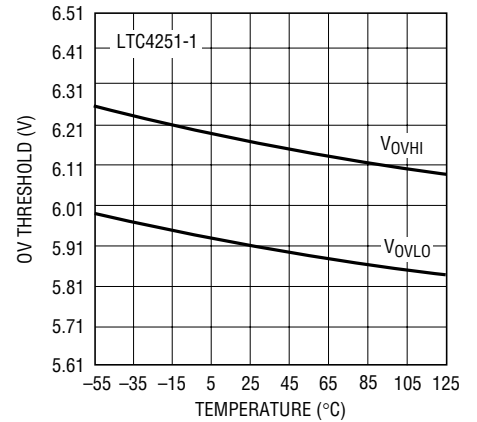
425112 G16

OV Threshold vs Temperature



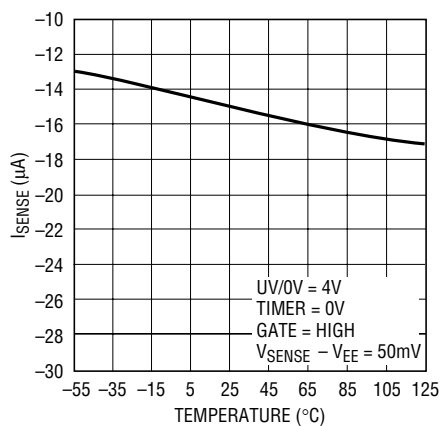
425112 G17

OV Threshold vs Temperature



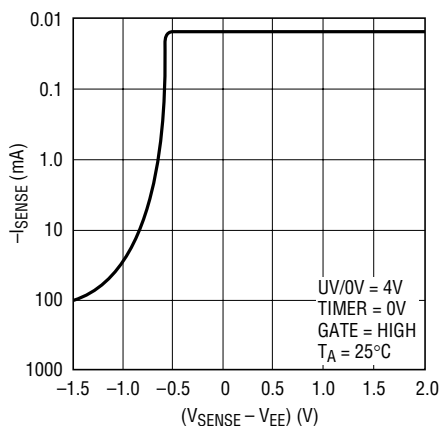
425112 G18

I_{SENSE} vs Temperature



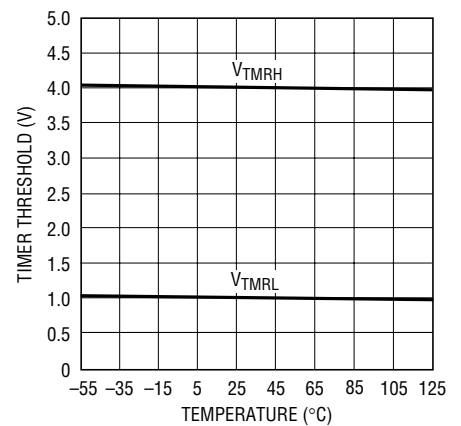
425112 G19

I_{SENSE} vs (V_{SENSE} - V_{EE})



425112 G20

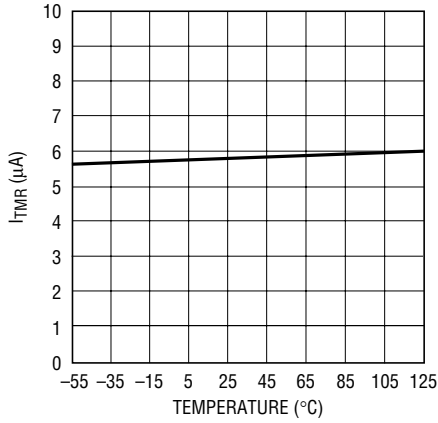
TIMER Threshold vs Temperature



425112 G21

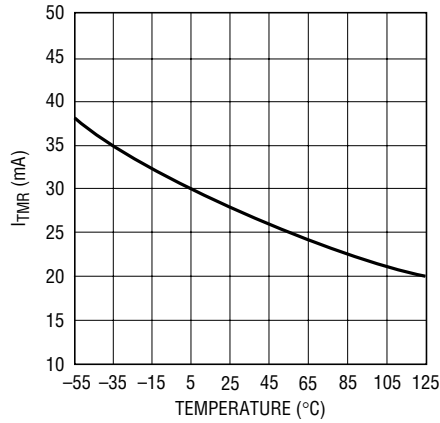
TYPICAL PERFORMANCE CHARACTERISTICS UV/OV = 4V refers to UV = 4V for the LTC4251-2.

I_{TMR} (Initial Cycle, Sourcing) vs Temperature



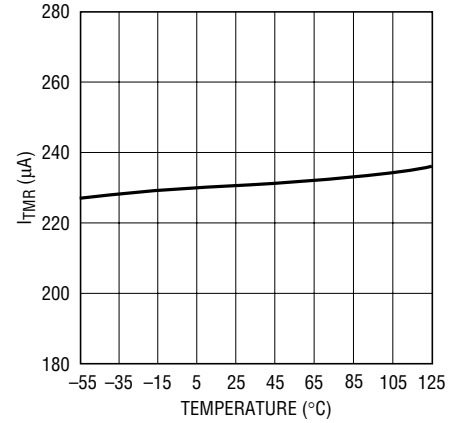
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I_{TMR} (Initial Cycle, Sinking) vs Temperature



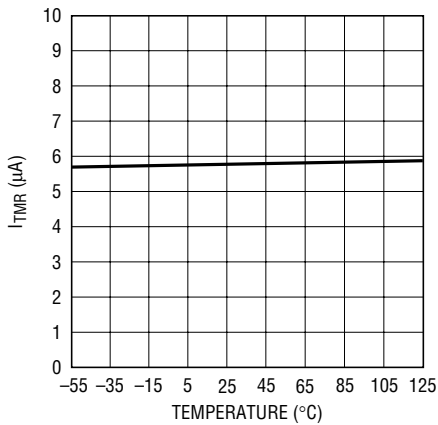
425112 G23

I_{TMR} (Circuit Breaking, Sourcing) vs Temperature



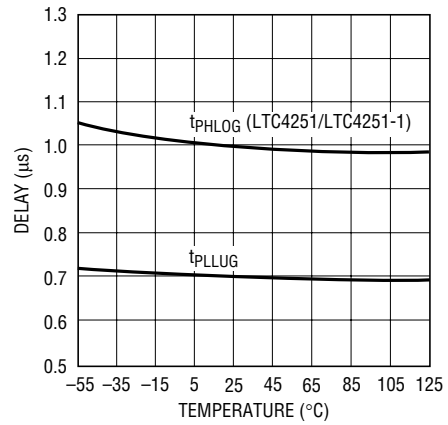
425112 G24

I_{TMR} (Cooling Cycle, Sinking) vs Temperature



425112 G25

t_{PLLUG} and t_{PHLOG} vs Temperature



425112 G26

PIN FUNCTIONS

UV/OV refers to the UV pin for the LTC4251-2. The OV comparator in the LTC4251-2 is disabled. All references in the text to overvoltage, OV, V_{OVHI} and V_{OVLO} do not apply to the LTC4251-2.

SENSE (Pin 1): Circuit Breaker/Current Limit SENSE Pin. Load current is monitored by sense resistor R_S connected between SENSE and V_{EE} , and controlled in three steps. If SENSE exceeds V_{CB} (50mV), the circuit breaker comparator activates a 230 μ A TIMER pin pull-up current. The LTC4251/LTC4251-1/LTC4251-2 latch off when C_T charges to 4V. If SENSE exceeds V_{ACL} (100mV), the analog current limit amplifier pulls GATE down and regulates the MOSFET current at V_{ACL}/R_S . In the event of a catastrophic short-circuit, SENSE may overshoot 100mV. If SENSE reaches V_{FCL} (200mV), the fast current limit comparator pulls GATE low with a strong pull-down. To disable the circuit breaker and current limit functions, connect SENSE to V_{EE} .

Kelvin-sense connections between the sense resistor and the V_{EE} and SENSE pins are strongly recommended, see Figure 6.

V_{EE} (Pin 2): Negative Supply Voltage Input. Connect this pin to the negative side of the power supply.

V_{IN} (Pin 3): Positive Supply Input. Connect this pin to the positive side of the supply through a dropping resistor. A shunt regulator typically clamps V_{IN} at 13V. An internal undervoltage lockout (UVLO) circuit holds GATE low until the V_{IN} pin is greater than V_{LKO} (9.2V), overriding UV/OV. If UV is high, OV is low and V_{IN} comes out of UVLO, TIMER starts an initial timing cycle before initiating a GATE ramp up. If V_{IN} drops below approximately 8.2V, GATE pulls low immediately.

TIMER (Pin 4): Timer Input. TIMER is used to generate a delay at start up, and to delay shutdown in the event of an output overload. TIMER starts an initial timing cycle when the following conditions are met: UV is high, OV is low, V_{IN} clears UVLO, TIMER pin is low, GATE is lower than V_{GATEL} and $V_{SENSE} - V_{EE} < V_{CB}$. A pull-up current of 5.8 μ A then charges C_T , generating a time delay. If C_T charges to V_{TMRH} (4V) the timing cycle terminates, TIMER quickly pulls low and GATE is activated.

If SENSE exceeds 50mV while GATE is high, a 230 μ A pull-up current charges C_T . If SENSE drops below 50mV before TIMER reaches 4V, a 5.8 μ A pull-down current slowly discharges C_T . In the event that C_T eventually integrates up to the 4V V_{TMRH} threshold, TIMER latches high with a 5.8 μ A pull-up source and GATE quickly pulls low. The LTC4251/LTC4251-1/LTC4251-2 fault latches may be cleared by either pulling TIMER low with an external device, or by pulling UV/OV below V_{UVLO} .

UV/OV (Pin 5): Undervoltage/Overvoltage Input. This dual function pin detects undervoltage as well as overvoltage. The high threshold at the UV comparator is set at V_{UVHI} with V_{UVHST} hysteresis. The high threshold at the OV comparator is set at V_{OVHI} with V_{OVHST} hysteresis. If $UV/OV < V_{UVLO}$ or $UV/OV > V_{OVHI}$, GATE pulls low. If $UV/OV > V_{UVHI}$ and $UV/OV < V_{OVLO}$, the LTC4251/LTC4251-1/LTC4251-2 attempt to start-up. The internal UVLO at V_{IN} always overrides UV/OV. A low at UV resets an internal fault latch. A high at OV pulls GATE low but does not reset the fault latch. A 1nF to 10nF capacitor at UV/OV eliminates transients and switching noise from affecting the UV/OV thresholds and prevents glitches at the GATE pin.

GATE (Pin 6): N-Channel MOSFET Gate Drive Output. This pin is pulled high by a 58 μ A current source. GATE is pulled low by invalid conditions at V_{IN} (UVLO), UV/OV, or the fault latch. GATE is actively servoed to control fault current as measured at SENSE. A compensation capacitor at GATE stabilizes this loop. A comparator monitors GATE to ensure that it is low before allowing an initial timing cycle, GATE ramp up after an overvoltage event, or restart after a current limit fault.

OPERATION

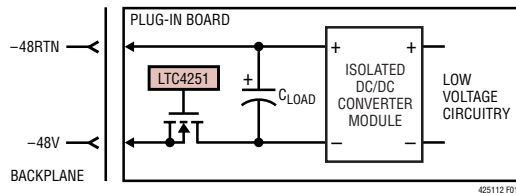


Figure 1. Basic LTC4251 Hot Swap Topology

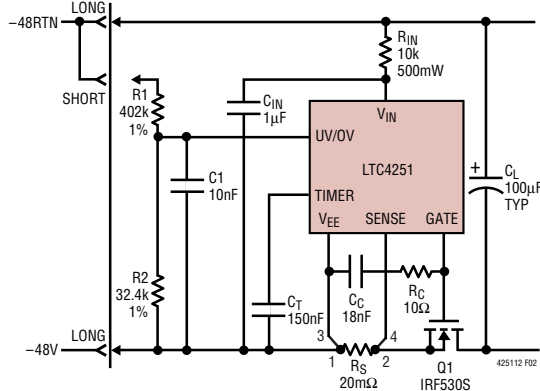


Figure 2. -48V, 2.5A Hot Swap Controller

Interlock Conditions

A start-up sequence commences once five initial “interlock” conditions are met:

1. The input voltage V_{IN} exceeds $9.2V$ (V_{LKO})
2. The voltage at UV/OV falls within the range of V_{UVHI} to V_{OVLO} ($UV > V_{UVHI}$, LTC4251-2)
3. The $(SENSE - V_{EE})$ voltage is $<50mV$ (V_{CB})
4. The voltage on the timer capacitor (C_T) is less than $1V$ (V_{TMRL})
5. GATE is less than $0.5V$ (V_{GATEL})

The first two conditions are continuously monitored and the latter three are checked prior to initial timing or GATE ramp-up. Upon exiting an OV condition, the TIMER pin voltage requirement is inhibited. Details are described in the Applications Information, Timing Waveforms section.

TIMER begins the start-up sequence by sourcing $5.8\mu A$ into C_T . If V_{IN} or UV/OV falls out of range, the start-up cycle stops and TIMER discharges C_T to less than $1V$, then waits until the aforementioned conditions are once again met. If C_T successfully charges to $4V$, TIMER pulls low and GATE

is released. GATE sources $58\mu A$ (I_{GATE}), charging the MOSFET gate and associated capacitance.

Two modes of operation are possible during the time the MOSFET is first turning on, depending on the values of external components, MOSFET characteristics and nominal design current. One possibility is that the MOSFET will turn on gradually so that the inrush into the load capacitance remains a low value. The output will simply ramp to $-48V$ and the MOSFET will be fully enhanced. A second possibility is that the load current exceeds the current limit threshold of $100mV/R_S$. In this case, the LTC4251/LTC4251-1/LTC4251-2 will ramp the output by sourcing $100mV/R_S$ current into the load capacitance. It is important to set the timer delay so that, regardless of which start-up mode is used, the start-up time is less than the TIMER delay time. If this condition is not met, the LTC4251/LTC4251-1/LTC4251-2 may shut down after one TIMER delay.

Board Removal

If the board is withdrawn from the card cage, the UV/OV divider is the first to lose connection. This shuts off the MOSFET and commutates the flow of current in the connector. When the power pins subsequently separate, there is no arcing.

Current Control

Three levels of protection handle short-circuit and overload conditions. Load current is monitored by SENSE and resistor R_S . There are three distinct thresholds at SENSE: $50mV$ for a timed circuit breaker function; $100mV$ for an analog current limit loop; and $200mV$ for a fast, feedforward comparator which limits peak current in the event of a catastrophic short-circuit.

If, owing to an output overload, the voltage drop across R_S exceeds $50mV$, TIMER sources $230\mu A$ into C_T . C_T eventually charges to a $4V$ threshold and the LTC4251/LTC4251-1/LTC4251-2 latch off. If the overload goes away and SENSE measures less than $50mV$, C_T slowly discharges ($5.8\mu A$). In this way the circuit breaker function will also respond to low duty cycle overloads, and accounts for fast heating and slow cooling characteristic of the MOSFET.

OPERATION

Higher overloads are handled by an analog current limit loop. If the drop across R_S reaches 100mV, the current limiting loop servos the MOSFET gate and maintains a constant output current of $100\text{mV}/R_S$. Note that because $\text{SENSE} > 50\text{mV}$, TIMER charges C_T during this time and the LTC4251/LTC4251-1/LTC4251-2 will eventually shut down.

Low impedance failures on the load side of the LTC4251/LTC4251-1/LTC4251-2 coupled with 48V or more driving potential can produce current slew rates well in excess of $50\text{A}/\mu\text{s}$. Under these conditions, overshoot is inevitable. A fast SENSE comparator with a threshold of 200mV detects overshoot and pulls GATE low much harder and hence much faster than can the weaker current limit loop. The $100\text{mV}/R_S$ current limit loop then takes over, and servos the current as previously described. As before, TIMER runs and latches the LTC4251/LTC4251-1/LTC4251-2 off when C_T reaches 4V.

The LTC4251/LTC4251-1/LTC4251-2 circuit breaker latch is reset by either pulling UV/OV momentarily low, or dropping the input voltage V_{IN} below the internal UVLO threshold of 8.2V.

Although short-circuits are the most obvious fault type, several operating conditions may invoke overcurrent protection. Noise spikes from the backplane or load, input steps caused by the connection of a second, higher voltage supply, transient currents caused by faults on adjacent circuit boards sharing the same power bus, or the insertion of non-hot swappable products could cause higher than anticipated input current and temporary detection of an overcurrent condition. The action of TIMER and C_T rejects these events allowing the LTC4251/LTC4251-1/LTC4251-2 to “ride out” temporary overloads and disturbances that would trip a simple current comparator and in some cases, blow a fuse.

APPLICATIONS INFORMATION (Refer to Block Diagram)

SHUNT REGULATOR

A fast responding regulator shunts the LTC4251/LTC4251-1/LTC4251-2 V_{IN} pin. Power is derived from -48RTN by an external current limiting resistor. The shunt regulator clamps V_{IN} to 13V (V_Z). A $1\mu\text{F}$ decoupling capacitor at V_{IN} filters supply transients and contributes a short delay at start-up. A $10\text{k } 1/2\text{W}$ (R_{IN}) resistor can be two $5\text{k } 1/4\text{W}$ resistors in series.

INTERNAL UNDERVOLTAGE LOCKOUT (UVLO)

Internal circuitry monitors V_{IN} for undervoltage. The exact thresholds are defined by V_{LKO} and its hysteresis, V_{LKH} . When V_{IN} rises above 9.2V (V_{LKO}) the chip is enabled; below 8.2V ($V_{LKO}-V_{LKH}$) it is disabled and GATE is pulled low. The UVLO function at V_{IN} should not be confused with the UV/OV pin. These are completely separate functions.

UV/OV COMPARATORS

Two hysteretic comparators for detecting under- and overvoltage conditions, with the following thresholds, monitor the dual function UV/OV pin:

UV turning on at V_{UVHI}

UV turning off at V_{UVLO}

OV turning off at V_{OVHI}

OV turning on at V_{OVLO}

The UV and OV trip point ratio for LTC4251 is designed to match the standard telecom operating range of 43V to 75V. The LTC4251-2 implements a UV threshold of 43V only.

A divider (R_1 , R_2) is used to scale the supply voltage. Using $R_1 = 402\text{k}$ and $R_2 = 32.4\text{k}$ gives a typical operating range of 43.2V to 74.4V. The under- and overvoltage shutdown thresholds are then 39.2V and 82.5V. 1% divider resistors are recommended to preserve threshold accuracy. The same resistor values can be used for the LTC4251-2.

APPLICATIONS INFORMATION

The R1-R2 divider values shown in the Typical Application set a standing current of slightly more than 100 μ A, and define an impedance at UV/OV of 30k. In most applications, 30k impedance coupled with 300mV UV hysteresis makes the LTC4251/LTC4251-1/LTC4251-2 insensitive to noise. If more noise immunity is desired, add a 1nF to 10nF filter capacitor from UV/OV to V_{EE}.

The UV and OV trip point thresholds for the LTC4251-1 are designed to encompass the standard telecom operating range of -36V to -72V.

A divider (R1, R2) is used to scale the supply voltage. Using R1 = 442k and R2 = 34.8k gives a typical operating range of 33.2V to 81V. The typical under- and overvoltage shutdown thresholds are then 29.6V and 84.5V. 1% divider resistors are recommended to preserve threshold accuracy.

The R1-R2 divider values shown in the Typical Application set a standing current of slightly more than 100 μ A, and define an impedance at UV/OV of 32k. In most applications, 32k impedance coupled with 260mV UV hysteresis makes the LTC4251-1 insensitive to noise. If more noise immunity is desired, add a 1nF to 10nF filter capacitor from UV/OV to V_{EE}.

UV/OV OPERATION

A low input to the UV comparator will reset the chip and pull the GATE and TIMER pins low. A low-to-high UV transition will initiate an initial timing sequence if the three remaining interlock conditions are met.

Overvoltage conditions detected by the OV comparator will also pull GATE low, thereby shutting down the load, but it will not reset the circuit breaker latch. Returning the supply voltage to an acceptable range restarts the GATE pin provided all interlock conditions except TIMER are met.

TIMER

The operation of the TIMER pin is somewhat complex as it handles several key functions. A capacitor, C_T, is used at TIMER to provide timing for the LTC4251/LTC4251-1/LTC4251-2. Four different charging and discharging modes are available at TIMER:

1. 5.8 μ A slow charge; initial timing delay
2. 230 μ A fast charge; circuit breaker delay
3. 5.8 μ A slow discharge; circuit breaker “cool-off”
4. Low impedance switch; resets capacitor after initial timing delay, in undervoltage lockout, and in overvoltage

For initial startup, the 5.8 μ A pull-up is used. The low impedance switch is turned off and the 5.8 μ A current source is enabled when the four interlock conditions are met. C_T charges to 4V in a time period given by:

$$t = \frac{4V \cdot C_T}{5.8\mu A} \quad (1)$$

When C_T reaches 4V (V_{TMRH}), the low impedance switch turns on and discharges C_T. The GATE output is enabled and the load turns on.

CIRCUIT BREAKER TIMER OPERATION

If the SENSE pin detects more than 50mV across R_S, the TIMER pin charges C_T with 230 μ A. If C_T charges to 4V, the GATE pin pulls low and the LTC4251/LTC4251-1/LTC4251-2 latch off. The part remains latched off until either the UV/OV pin is momentarily pulsed low, or V_{IN} dips into UVLO and is then restored. The circuit breaker timeout period is given by

$$t = \frac{4V \cdot C_T}{230\mu A} \quad (2)$$

Intermittent overloads may exceed the 50mV threshold at SENSE, but if their duration is sufficiently short TIMER will not reach 4V and the LTC4251/LTC4251-1/LTC4251-2 will not latch off. To handle this situation, the TIMER discharges C_T slowly with a 5.8 μ A pull-down whenever the SENSE voltage is less than 50mV. Therefore any intermittent overload with an aggregate duty cycle of 2.5% or more will eventually trip the circuit breaker and latch off the LTC4251/LTC4251-1/LTC4251-2. Figure 3 shows the circuit breaker response time in seconds normalized to 1 μ F. The asymmetric charging and discharging of C_T is a fair gauge of MOSFET heating.

APPLICATIONS INFORMATION

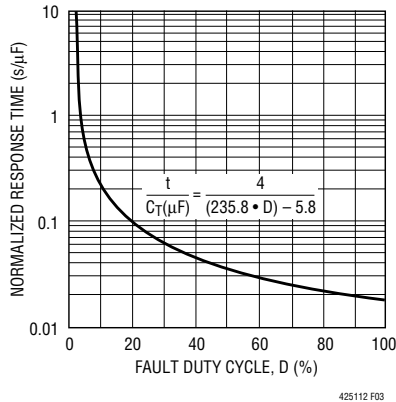


Figure 3. Circuit Breaker Response Time

GATE

GATE is pulled low to V_{EE} under any of the following conditions: in UVLO, during the initial timing cycle, in an overvoltage condition, or when the LTC4251/LTC4251-1/LTC4251-2 are latched off after a short-circuit. When GATE turns on, a $58\mu\text{A}$ current source charges the MOSFET gate and any associated external capacitance. V_{IN} limits gate drive to no more than 14.5V.

Gate-drain capacitance (C_{GD}) feed through at the first abrupt application of power can cause a gate-source voltage sufficient to turn on the MOSFET. A unique circuit pulls GATE low with practically no usable voltage at V_{IN} , and eliminates current spikes at insertion. A large external gate-source capacitor is thus unnecessary for the purpose of compensating C_{GD} . Instead, a smaller value ($\geq 10\text{nF}$) capacitor C_C is adequate. C_C also provides compensation for the analog current limit loop.

SENSE

The SENSE pin is monitored by the circuit breaker (CB) comparator, the analog current limit (ACL) amplifier, and the fast current limit (FCL) comparator. Each of these three measures the potential of SENSE relative to V_{EE} . If SENSE exceeds 50mV, the CB comparator activates the $230\mu\text{A}$ TIMER pull-up. At 100mV, the ACL amplifier servos the MOSFET current, and at 200mV the FCL comparator abruptly pulls GATE low in an attempt to bring the MOSFET current under control. If any of these conditions persists long enough for TIMER to charge C_T to 4V (see Equation (2)), the LTC4251/LTC4251-1/LTC4251-2 latch off and pull GATE low.

If the SENSE pin encounters a voltage greater than 100mV, the ACL amplifier will servo GATE downwards in an attempt to control the MOSFET current. Since GATE overdrives the MOSFET in normal operation, the ACL amplifier needs time to discharge GATE to the threshold of the MOSFET. For a mild overload, the ACL amplifier can control the MOSFET current, but in the event of a severe overload the current may overshoot. At SENSE = 200mV, the FCL comparator takes over, quickly discharging the GATE pin to near V_{EE} potential. FCL then releases, and the ACL amplifier takes over. All the while TIMER is running. The effect of FCL is to add a nonlinear response to the control loop in favor of reducing MOSFET current.

Owing to inductive effects in the system, FCL typically overcorrects the current limit loop, and GATE undershoots. A zero in the loop (resistor R_C in series with the gate capacitor) helps the ACL amplifier recover.

SHORT-CIRCUIT OPERATION

Circuit behavior arising from a load-side low impedance short is shown in Figure 4. Initially, the current overshoots the analog current limit level of $V_{SENSE} = 100\text{mV}$ (Trace 2) as the GATE pin works to bring V_{GS} under control (Trace 3). The overshoot glitches the backplane in the negative direction, and when the current is reduced to $100\text{mV}/R_S$ the backplane responds by glitching in the positive direction.

TIMER commences charging C_T (Trace 4) while the analog current limit loop maintains the fault current at $100\text{mV}/R_S$, which in this case is 5A (Trace 2). Note that the backplane voltage (Trace 1) sags under load. When C_T reaches 4V, GATE turns off, the load current drops to zero and the backplane rings up to over 100V. The positive peak is usually limited by avalanche breakdown in the MOSFET, and can be further limited by adding a zener diode across the input from -48V to -48RTN , such as Diodes Inc. SMAT70A.

A low-impedance short on one card may influence the behavior of others sharing the same backplane. The initial glitch and backplane sag as seen in Figure 4, Trace 1, can rob charge from output capacitors on adjacent cards. When the faulty card shuts down, current flows in to refresh the

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capacitors. If LTC4251, LTC4251-1 or LTC4251-2s are used throughout, they respond by limiting the inrush current to a value of $100\text{mV}/R_S$. If C_T is sized correctly, the capacitors will recharge long before C_T times out.

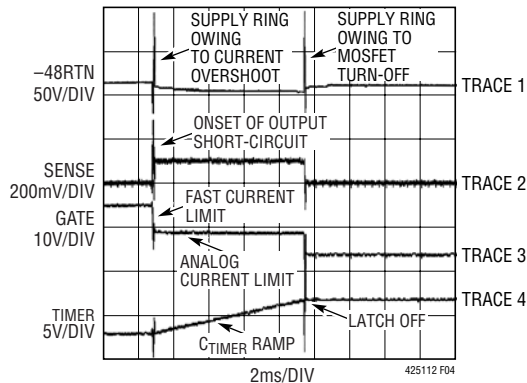


Figure 4. Output Short-Circuit Behavior
(All Waveforms are Referenced to V_{EE})

MOSFET SELECTION

The external MOSFET switch must have adequate safe operating area (SOA) to charge the load capacitance on start-up and handle short-circuit conditions until TIMER latchoff. These considerations take precedence over DC current ratings. A MOSFET with adequate SOA for a given application can always handle the required current, but the opposite cannot be said. Consult the manufacturer's MOSFET data sheet for safe operating area and effective transient thermal impedance curves.

MOSFET selection is a three-step process. First, R_S is calculated, and then the time required to charge the load capacitance is determined. This timing, along with the maximum short-circuit current and maximum input voltage defines an operating point that is checked against the MOSFET's SOA curve.

To begin a design, first specify the required load current and load capacitance, I_L and C_L . The circuit breaker current trip point ($50\text{mV}/R_S$) should be set to accommodate the maximum load current. Note that maximum input current to a DC/DC converter is expected at $V_{\text{SUPPLY (MIN)}}$. R_S is given by:

$$R_S = \frac{40\text{mV}}{I_L(\text{MAX})} \quad (3)$$

where 40mV represents the guaranteed minimum circuit breaker threshold.

During the initial charging process, the LTC4251/LTC4251-1/LTC4251-2 may operate the MOSFET in current limit, forcing 80mV to 120mV across R_S . The minimum inrush current is given by:

$$I_{\text{INRUSH(MIN)}} = \frac{80\text{mV}}{R_S} \quad (4)$$

Maximum short-circuit current limit is calculated using maximum V_{SENSE} , or:

$$I_{\text{SHORT-CIRCUIT(MAX)}} = \frac{120\text{mV}}{R_S} \quad (5)$$

The TIMER capacitor C_T must be selected based on the slowest expected charging rate; otherwise TIMER might time out before the load capacitor is fully charged. A value for C_T is calculated based on the maximum time it takes the load capacitor to charge. That time is given by:

$$t_{\text{CL CHARGE}} = \frac{C \cdot V}{I} = \frac{C_L \cdot V_{\text{SUPPLY(MAX)}}}{I_{\text{INRUSH(MIN)}}} \quad (6)$$

Substituting Equation (4) for $I_{\text{INRUSH(MIN)}}$ and equating (6) with (2) gives:

$$C_T = \frac{C_L \cdot V_{\text{SUPPLY(MAX)}} \cdot R_S \cdot 230\mu\text{A}}{(4\text{V} \cdot 80\text{mV})} \quad (7)$$

Returning to Equation (2), the TIMER period is calculated and used in conjunction with $V_{\text{SUPPLY(MAX)}}$ and $I_{\text{SHORT-CIRCUIT(MAX)}}$ to check the SOA curves of a prospective MOSFET.

As a numerical design example, consider a 30W load, which requires 1A input current at 36V. If $V_{\text{SUPPLY(MAX)}} = 72\text{V}$ and $C_L = 100\mu\text{F}$, Equation (3) gives $R_{\text{SENSE}} = 40\text{m}\Omega$; Equation (7) gives $C_T = 207\text{nF}$. To account for errors in R_{SENSE} , C_T , TIMER current ($230\mu\text{A}$) and TIMER threshold (4V), the calculated value should be multiplied by 1.5, giving a nearest standard value of $C_T = 330\text{nF}$.

If a short-circuit occurs, a current of up to $120\text{mV}/40\text{m}\Omega = 3\text{A}$ will flow in the MOSFET for 5.7ms as dictated by

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$C_T = 330\text{nF}$ in Equation (2). The MOSFET must be selected based on this criterion. The IRF530S can handle 100V and 3A for 10ms, and is safe to use in this application.

SUMMARY OF DESIGN FLOW

To summarize the design flow, consider the application shown in Figure 2, which was designed for 50W:

Calculate maximum load current: $50\text{W}/36\text{V} = 1.4\text{A}$; allowing 83% converter efficiency, $I_{IN(\text{MAX})} = 1.7\text{A}$.

Calculate R_S : from Equation (3) $R_S = 20\text{m}\Omega$.

Calculate C_T : from Equation (7) $C_T = 150\text{nF}$ (including 1.5X correction factor).

Calculate TIMER period: from Equation (2) the short-circuit time-out period is $t = 2.6\text{ms}$.

Calculate maximum short-circuit current: from Equation (5) maximum short-circuit current could be as high as $120\text{mV}/20\text{m}\Omega = 6\text{A}$.

Consult MOSFET SOA curves: the IRF530S can handle 6A at 72V for 5ms, so it is safe to use in this application.

FREQUENCY COMPENSATION

The LTC4251/LTC4251-1/LTC4251-2 typical frequency compensation network for the analog current limit loop is a series R_C (10Ω) and C_C connected to V_{EE} . Figure 5 depicts the relationship between the compensation capacitor C_C and the MOSFET's C_{ISS} . The line in Figure 5 is used to select a starting value for C_C based upon the MOSFET's C_{ISS} specification. Optimized values for C_C are shown for several popular MOSFETs. Differences in the optimized value of C_C versus the starting value are small. Nevertheless, compensation values should be verified by board level short-circuit testing.

As seen in Figure 4 previously, at the onset of a short-circuit event, the input supply voltage can ring dramatically owing to series inductance. If this voltage avalanches the MOSFET, current continues to flow through the MOSFET to the output. The analog current limit loop cannot control this current flow and therefore the loop undershoots. This effect cannot be eliminated by frequency compensation. A

zener diode is required to clamp the input supply voltage and prevent MOSFET avalanche.

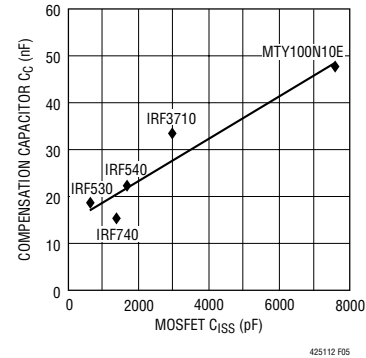


Figure 5. Recommended Compensation Capacitor C_C vs MOSFET C_{ISS}

SENSE RESISTOR CONSIDERATIONS

For proper circuit breaker operation, Kelvin-sense PCB connections between the sense resistor and the V_{EE} and SENSE pins are strongly recommended. The drawing in Figure 6 illustrates the correct way of making connections between the LTC4251/LTC4251-1/LTC4251-2 and the sense resistor. PCB layout should be balanced and symmetrical to minimize wiring errors. In addition, the PCB layout for the sense resistor should include good thermal management techniques for optimal sense resistor power dissipation.

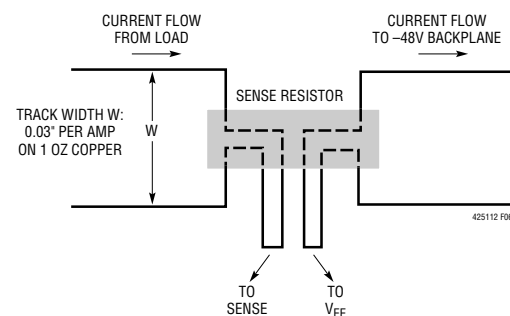


Figure 6. Making PCB Connections to the Sense Resistor

TIMING WAVEFORMS

System Power-Up

Figure 7 details the timing waveforms for a typical power-up sequence in the case where a board is already installed in the backplane and system power is applied abruptly. At time point 1, the supply ramps up, together with UV/OV

APPLICATIONS INFORMATION

and V_{OUT} . V_{IN} follows at a slower rate as set by the V_{IN} bypass capacitor. At time point 2, V_{IN} exceeds V_{LKO} and the internal logic checks for $V_{UVHI} < UV/OV < V_{OVLO}$, $TIMER < V_{TMRL}$, $GATE < V_{GATEL}$ and $SENSE < V_{CB}$. When all conditions are met, an initial timing cycle starts and the $TIMER$ capacitor is charged by a $5.8\mu A$ current source pull-up. At time point 3, $TIMER$ reaches the V_{TMRH} threshold and the initial timing cycle terminates. The $TIMER$ capacitor is then quickly discharged. At time point 4, the V_{TMRL} threshold is reached and the conditions of $GATE < V_{GATEL}$ and $SENSE < V_{CB}$ must be satisfied before a start-up cycle is allowed to begin. $GATE$ sources $58\mu A$ into the external MOSFET gate and compensation network. When the $GATE$ voltage reaches the MOSFET's threshold, current begins flowing into the load capacitor. At time point 5, the $SENSE$ voltage ($V_{SENSE} - V_{EE}$) reaches the V_{CB} threshold and activates the $TIMER$. The $TIMER$ capacitor is charged by a $230\mu A$ current-source pull-up. At time point 6, the analog current limit loop activates. Between time point 6 and time point 7, the $GATE$ voltage is held essentially constant and the sense voltage is regulated at V_{ACL} . As the load capacitor nears full charge, its current begins to decline. At time point 7, the load current falls and the sense voltage drops below V_{ACL} . The analog current limit loop shuts off and the $GATE$ pin ramps further. At time point 8, the sense voltage drops below V_{CB} and $TIMER$ now discharges through a $5.8\mu A$ current source pull-down. At time point 9, $GATE$ reaches its maximum voltage as determined by V_{IN} .

Live Insertion with Short Pin Control of UV/OV

In this example as shown in Figure 8, power is delivered through long connector pins whereas the UV/OV divider makes contact through a short pin. This ensures the power connections are firmly established before the LTC4251/LTC4251-1/LTC4251-2 are activated. At time point 1, the power pins make contact and V_{IN} ramps through V_{LKO} . At time point 2, the UV/OV divider makes contact and its voltage exceeds V_{UVHI} . In addition, the internal logic checks for $V_{UVHI} < UV/OV < V_{OVHI}$, $TIMER < V_{TMRL}$, $GATE < V_{GATEL}$ and $SENSE < V_{CB}$. When all conditions are met, an initial timing cycle starts and the $TIMER$ capacitor is charged by a $5.8\mu A$ current source pull-up. At time point 3, $TIMER$ reaches the V_{TMRH} threshold and the initial

timing cycle terminates. The $TIMER$ capacitor is then quickly discharged. At time point 4, the V_{TMRL} threshold is reached and the conditions of $GATE < V_{GATEL}$ and $SENSE < V_{CB}$ must be satisfied before a start-up cycle is allowed to begin. $GATE$ sources $58\mu A$ into the external MOSFET gate and compensation network. When the $GATE$ voltage reaches the MOSFET's threshold, current begins flowing into the load capacitor. At time point 5, the $SENSE$ voltage ($V_{SENSE} - V_{EE}$) reaches the V_{CB} threshold and activates the $TIMER$. The $TIMER$ capacitor is charged by a $230\mu A$ current source pull-up. At time point 6, the analog current limit loop activates. Between time point 6 and time point 7, the $GATE$ voltage is held essentially constant and the sense voltage is regulated at V_{ACL} . As the load capacitor nears full charge, its current begins to decline. At time point 7, the load current falls and the sense voltage drops below V_{ACL} . The analog current limit loop shuts off and the $GATE$ pin ramps further. At time point 8, the sense voltage drops below V_{CB} and $TIMER$ now discharges through a $5.8\mu A$ current source pull-down. At time point 9, $GATE$ reaches its maximum voltage as determined by V_{IN} .

Undervoltage Lockout Timing

In Figure 9, when UV/OV drops below V_{UVLO} (time point 1), $TIMER$ and $GATE$ pull low. If current has been flowing, the $SENSE$ pin voltage decreases to zero as $GATE$ collapses. When UV/OV recovers and clears V_{UVHI} (time point 2), an initial time cycle begins followed by a start-up cycle.

Undervoltage Timing with Overvoltage Glitch

In Figure 10, when UV/OV clears V_{UVHI} (time point 1), an initial timing cycle starts. If the system bus voltage overshoots V_{OVHI} as shown at time point 2, $TIMER$ discharges. At time point 3, the supply voltage recovers and drops below the V_{OVLO} threshold. The initial timing cycle restarts followed by a start-up cycle.

Overvoltage Timing

During normal operation, if UV/OV exceeds V_{OVHI} as shown at time point 1 of Figure 11, the $TIMER$ status is unaffected. Nevertheless, $GATE$ pulls down and disconnects the load. At time point 2, UV/OV recovers and drops below the V_{OVLO} threshold. A gate ramp up cycle ensues.

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If the overvoltage glitch is long enough to deplete the load capacitor, a full start-up cycle may occur as shown between time points 3 through 6.

Timer Behavior

In Figure 12a, the TIMER capacitor charges at $230\mu\text{A}$ if the SENSE pin exceeds V_{CB} . It is discharged with $5.8\mu\text{A}$ if the

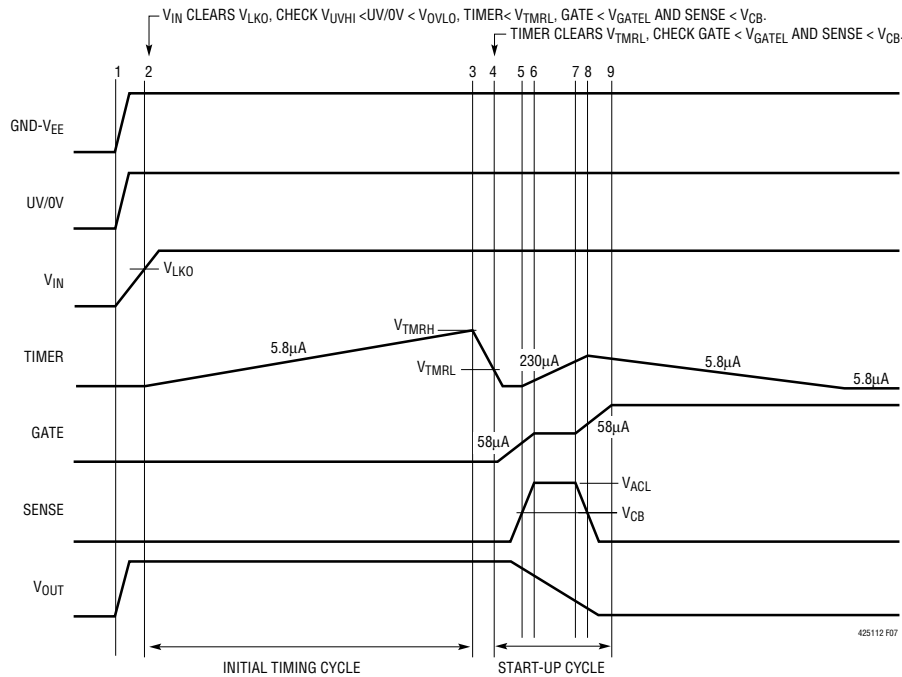


Figure 7. System Power-Up Timing (All Waveforms are Referenced to V_{EE})

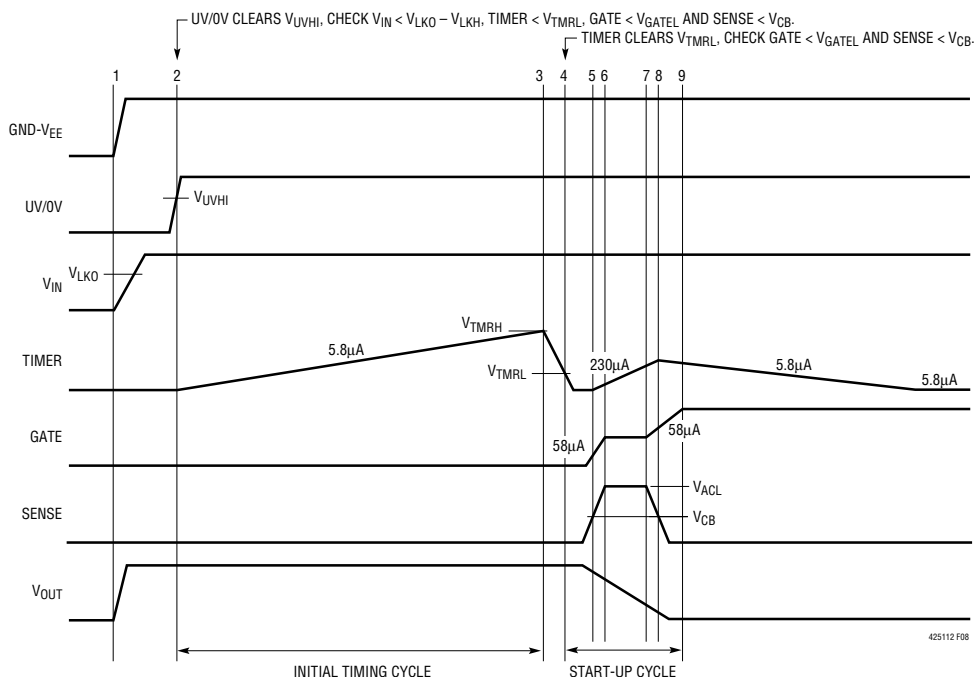


Figure 8. Power-Up Timing with a Short-Pin (All Waveforms are Referenced to V_{EE})

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SENSE pin is less than V_{CB} . In Figure 12b, when TIMER exceeds V_{TMRH} , TIMER is latched high by the $5.8\mu\text{A}$ pull-up and GATE pulls down immediately. In Figure 12c, multiple momentary faults cause the TIMER capacitor to integrate until it latches.

Analog Current Limit and Fast Current Limit

In Figure 13a, when SENSE exceeds V_{ACL} , GATE is regulated by the analog current limit amplifier loop. When SENSE drops below V_{ACL} , GATE is allowed to pull up. In Figure 13b, when a severe fault occurs, SENSE exceeds V_{FCL} and GATE immediately pulls down until the analog

current amplifier can establish control. If TIMER reaches V_{TMRH} , GATE pulls low and latches off.

Resetting a Fault Latch

As shown in Figure 14, a latched fault is reset by either pulling UV/OV below V_{UVLO} or pulling TIMER below V_{TMRL} . An initial timing cycle is initiated if UV/OV is used for reset. If TIMER is used for reset, the initial timing cycle is skipped.

Internal Soft-Start

An internal soft-start feature ramps the positive input of the analog current limit amplifier during initial start-up.

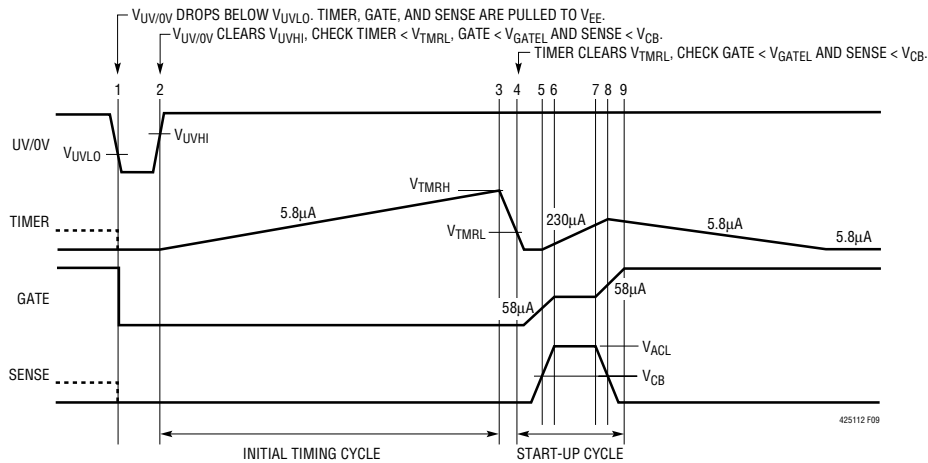


Figure 9. Undervoltage Lockout Timing (All Waveforms are Referenced to V_{EE})

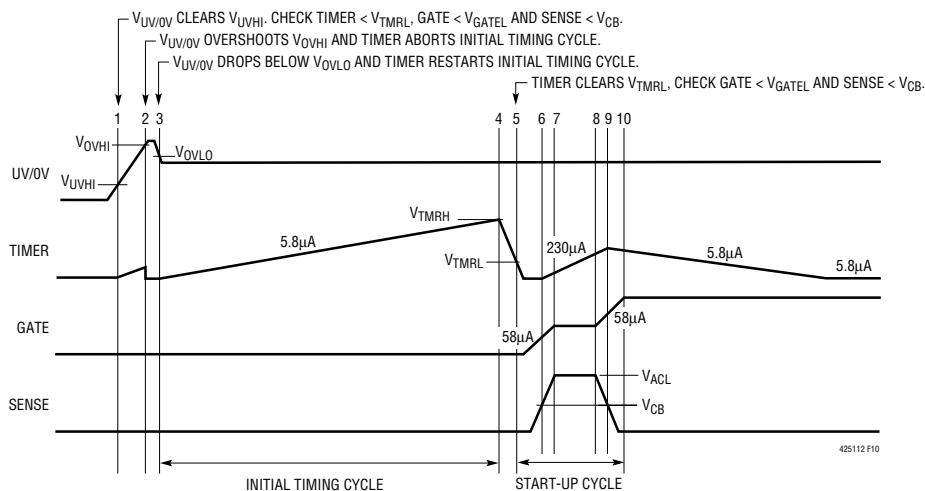


Figure 10. Undervoltage Timing with an Overvoltage Glitch (All Waveforms are Referenced to V_{EE})

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The ramp duration is approximately 200 μ s. This feature reduces load current dI/dt at start-up. As illustrated in Figure 15, soft-start is initiated by a TIMER transition from

V_{TMRH} to V_{TMRL} or when UV/OV falls below the V_{OVL0} threshold after an OV fault. After soft-start duration, load current is limited by V_{ACL}/R_S .

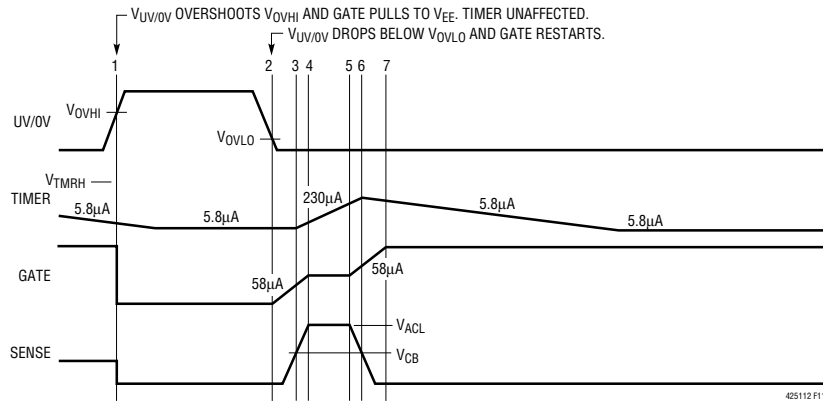
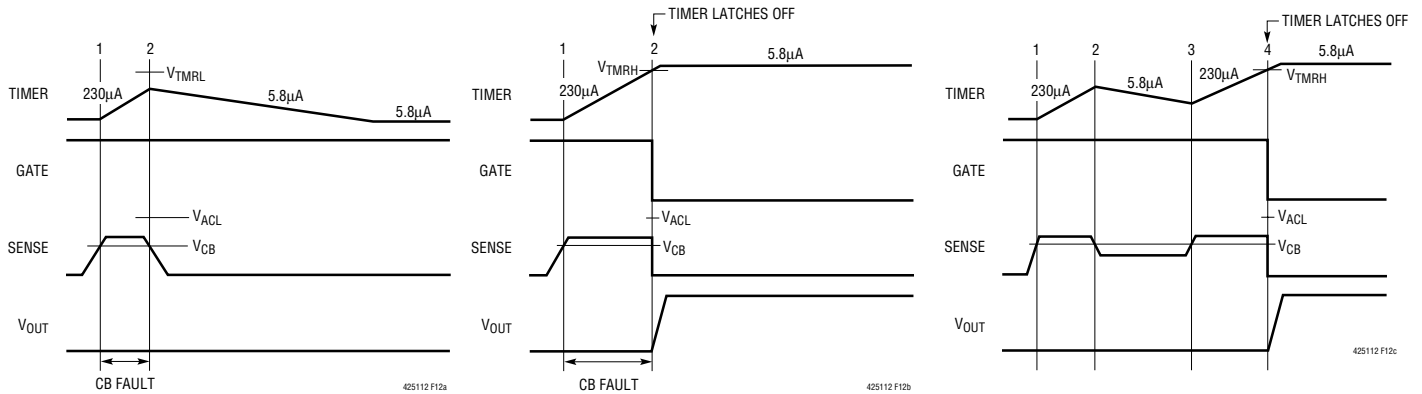


Figure 11. Overtiming Timing (All Waveforms are Referenced to V_{EE})

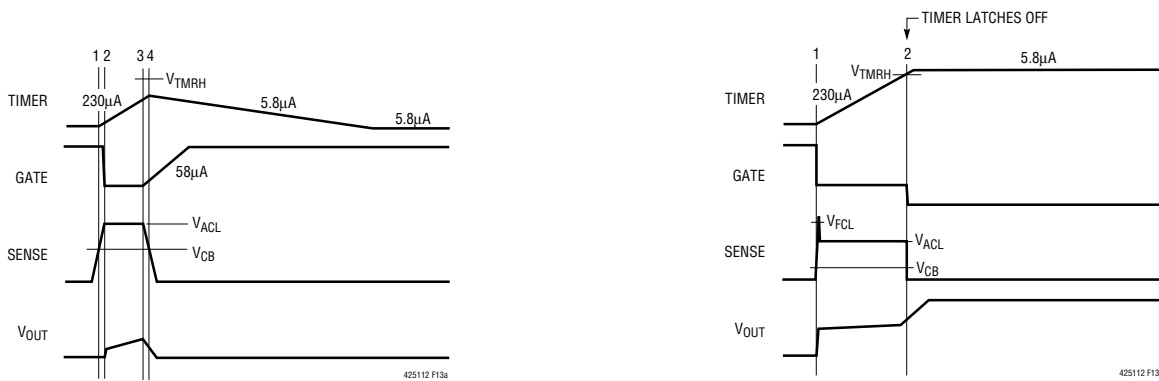


(12a) Momentary Circuit-Breaker Fault

(12b) Circuit-Breaker Time-Out

(12c) Multiple Circuit-Breaker Faults

Figure 12. Timer Behavior (All Waveforms are Referenced to V_{EE})



(13a) Analog Current Limit Fault

(13b) Fast Current Limit Fault

Figure 13. Current Limit Behavior (All Waveforms are Referenced to V_{EE})

APPLICATIONS INFORMATION

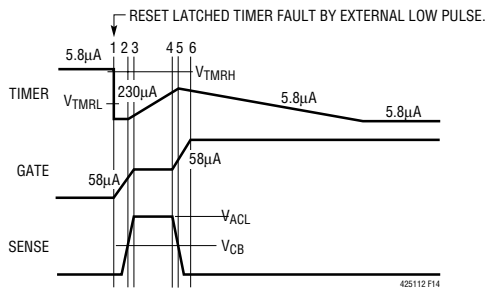


Figure 14. Latched Fault Reset Timing
(All Waveforms are Referenced to V_{EE})

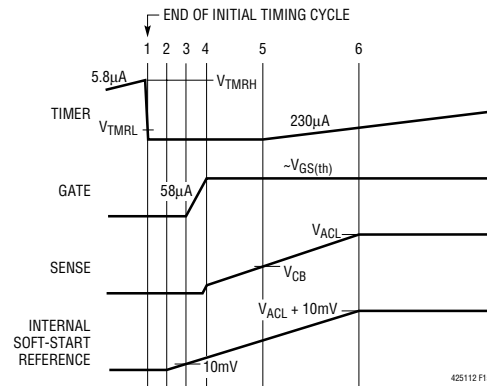
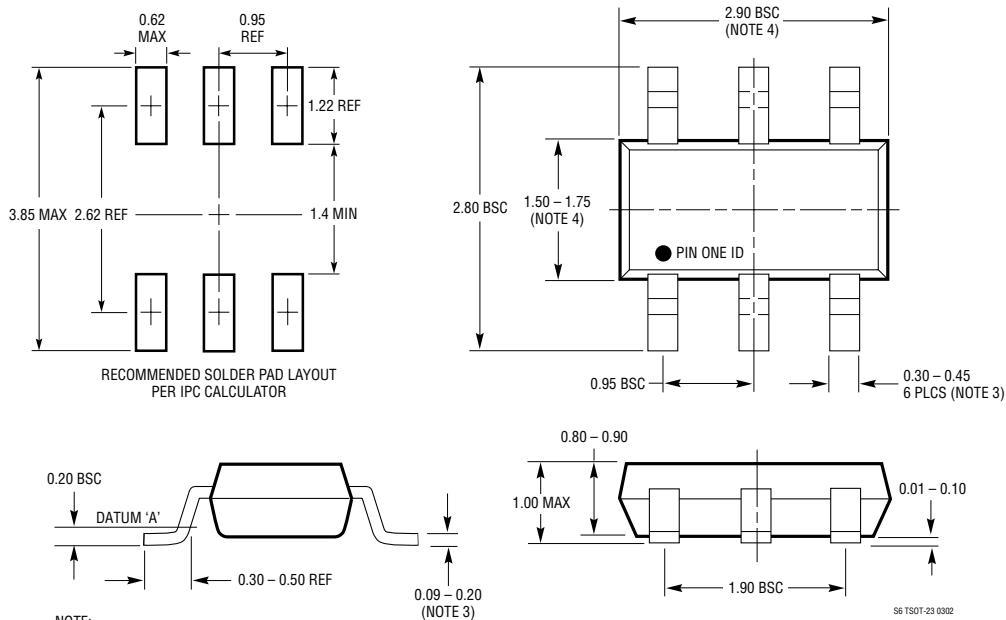


Figure 15. Internal Soft-Start Timing
(All Waveforms are Referenced to V_{EE})

PACKAGE DESCRIPTION

S6 Package 6-Lead Plastic TSOT-23 (Reference LTC DWG # 05-08-1636)



- NOTE:
1. DIMENSIONS ARE IN MILLIMETERS
 2. DRAWING NOT TO SCALE
 3. DIMENSIONS ARE INCLUSIVE OF PLATING
 4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
 5. MOLD FLASH SHALL NOT EXCEED 0.254mm
 6. JEDEC PACKAGE REFERENCE IS MO-193

TYPICAL APPLICATIONS

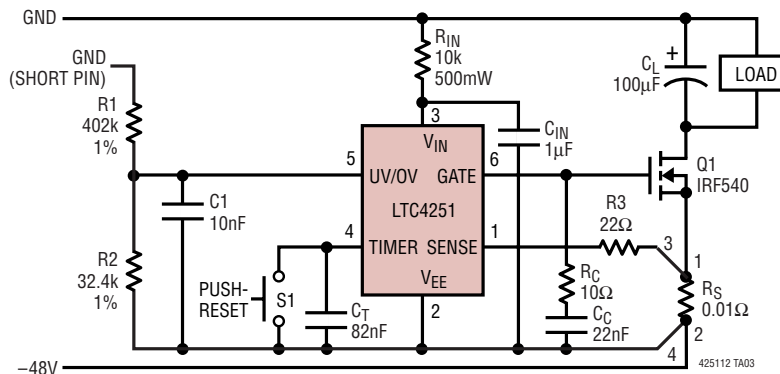


Figure 16. -48V/5A Application with Reverse SENSE Pin Limiting and Push-Reset at TIMER Pin

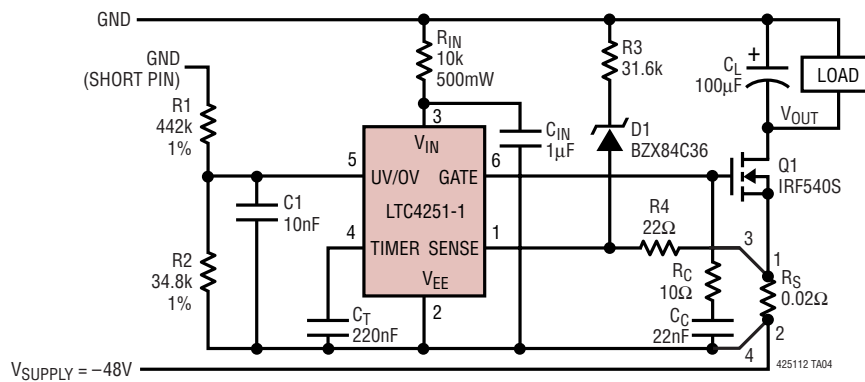


Figure 17. Power-Limited Circuit Breaker Application

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1640AH/LT1640AL	Negative High Voltage Hot Swap Controllers in SO-8	Negative High Voltage Supplies from -10V to -80V
LT1641-1/LT1641-2	Positive High Voltage Hot Swap Controllers in SO-8	Supplies from 9V to 80V, Latched Off/Autoretry
LTC1642	Fault Protected Hot Swap Controller	3V to 16.5V, Overvoltage Protection up to 33V
LTC1921	Dual -48V Supply and Fuse Monitor	±1V UV and ±1.5V OV Threshold Accuracy, ±200V Transient Protection, Drives Three Optoisolators for Status
LT4250	-48V Hot Swap Controller in SO-8	Active Current Limiting, Supplies from -20V to -80V
LTC4252-1/ LTC4252-2	Negative Voltage Hot Swap Controller in MSOP	Fast Active Current Limiting with Drain Accelerated Response, Supplies from -15V
LTC4253	Negative Voltage Hot Swap Controller with 3-Output Sequencer	Fast Active Current Limiting with Drain Accelerated Response, Supplies from -15V

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